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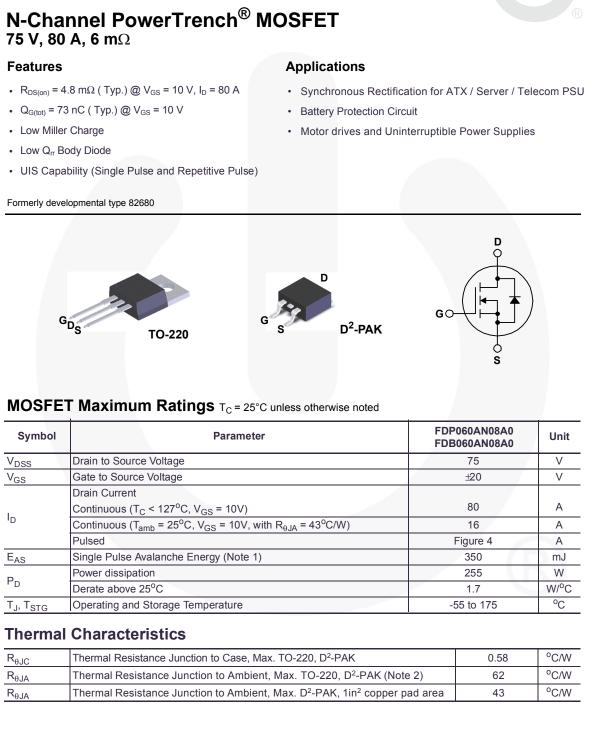


ON Semiconductor®

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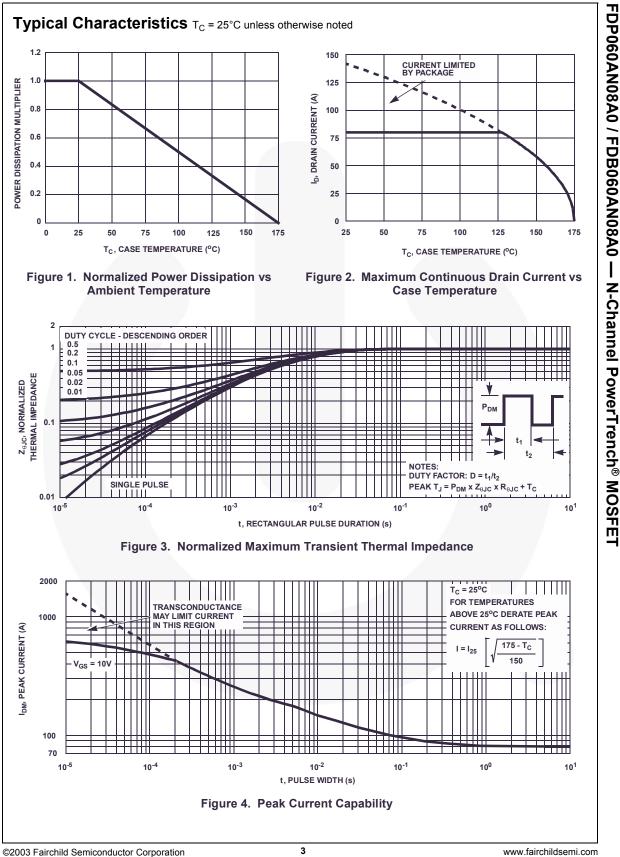
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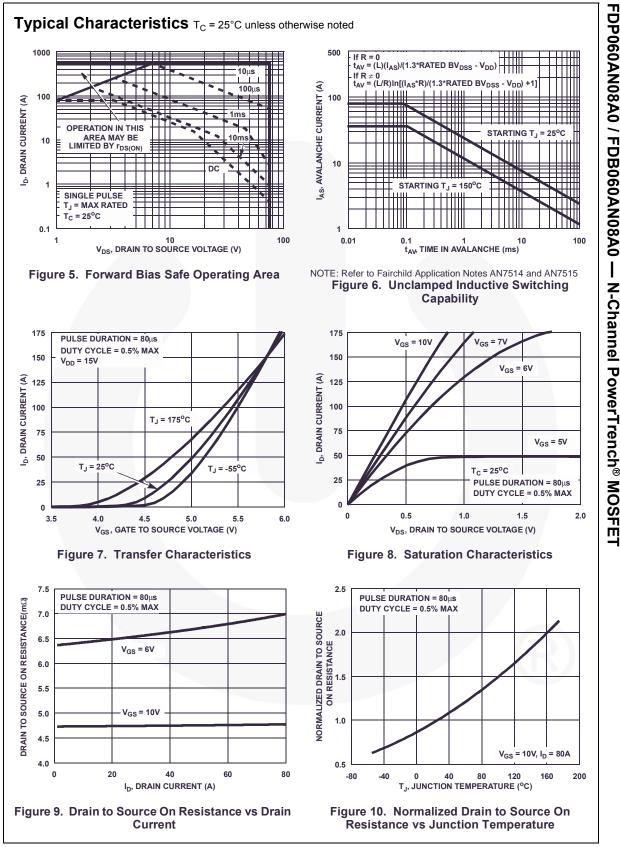
October 2013

Device Marking FDB060AN08A0		Device	Package	Reel Size 330 mm	Tape Width 24 mm		Quantity 800 units		
		FDB060AN08A0	D ² -PAK						
FDP060	FDP060AN08A0 FDP060AN08A0		TO-220 Tube		N/A		50 units		
Electric	al Char	acteristics T _C = 25°C	unless otherwise	e noted					
Symbol	Parameter		Test Conditions		Min	Тур	Мах	Unit	
Off Chara	acteristic	\$			•				
B _{VDSS}	Drain to Source Breakdown Voltage		I _D = 250μA, V	_{GS} = 0V	75	-	-	V	
				V _{DS} = 60V -		-	1	μΑ	
DSS Zero G		ate Voltage Drain Current	$V_{GS} = 0V$	T _C = 150 ^o C	-	-	250		
I _{GSS}	Gate to Source Leakage Current		V _{GS} = ±20V		-	-	±100	nA	
On Chara	acteristic	S							
V _{GS(TH)}	Gate to Source Threshold Voltage		V _{GS} = V _{DS} , I _D	= 250µA	2	-	4	V	
00(11)			$I_{\rm D}$ = 80A, V _{GS}		-	0.0048	0.006	1	
r _{DS(ON)}	Drain to Source On Resistance		$I_D = 40A, V_{GS}$		-	0.0066	0.010		
	Diani to S		I _D = 80A, V _{GS}	I _D = 80A, V _{GS} = 10V,		0.010	0.013	Ω	
	1		T _J = 175°C		-	0.010	0.010		
Dynamic	Characte	eristics							
C _{ISS}	Input Cap	Input Capacitance		- 0)/	-	5150	-	pF	
C _{OSS}	Output Ca	apacitance	— V _{DS} = 25V, V ₀ — f = 1MHz	_{GS} = 0V,	-	800	-	pF	
C _{RSS}	Reverse 7	Fransfer Capacitance			-	230	-	pF	
Q _{g(TOT)}	Total Gate	e Charge at 10V	V _{GS} = 0V to 1	0V		73	95	nC	
Q _{g(TH)}	Threshold	I Gate Charge	V_{GS} = 0V to 2	V V _{DD} = 40V	-	10	13	nC	
Q _{gs}		ource Gate Charge		I _D = 80A	-	29	-	nC	
Q _{gs2}		rge Threshold to Plateau		I _g = 1.0mA	-	19	-	nC	
Q _{gd}	Gate to D	rain "Miller" Charge			-	16	-	nC	
Switching	g Charac	teristics (V _{GS} = 10V)							
t _{ON}	Turn-On Time Turn-On Delay Time Rise Time				-	-	147	ns	
t _{d(ON)}			\neg	V _{DD} = 40V, I _D = 80A		19	-	ns	
t _r						79	-	ns	
t _{d(OFF)}	Turn-Off	Delay Time	$V_{GS} = 10V, R_{GS} = 3.9\Omega$		-	37	-	ns	
t _f	Fall Time					38	/	ns	
t _{OFF}	Turn-Off T	Turn-Off Time			-		113	ns	
Drain-So	urce Diod	de Characteristics							
V _{SD}	Source to	Source to Drain Diode Voltage			- /	-	1.25	V	
* SD			I _{SD} = 40A		-	-	1.0	V	
		Recovery Time	I_{SD} = 75A, dI_{SD}/dt = 100A/µs		-	-	37	ns	
t _{rr} Q _{RR}	ID	Recovered Charge	I _{SD} = 75A, dI _{SD} /dt = 100A/μs		-	-	38	nC	

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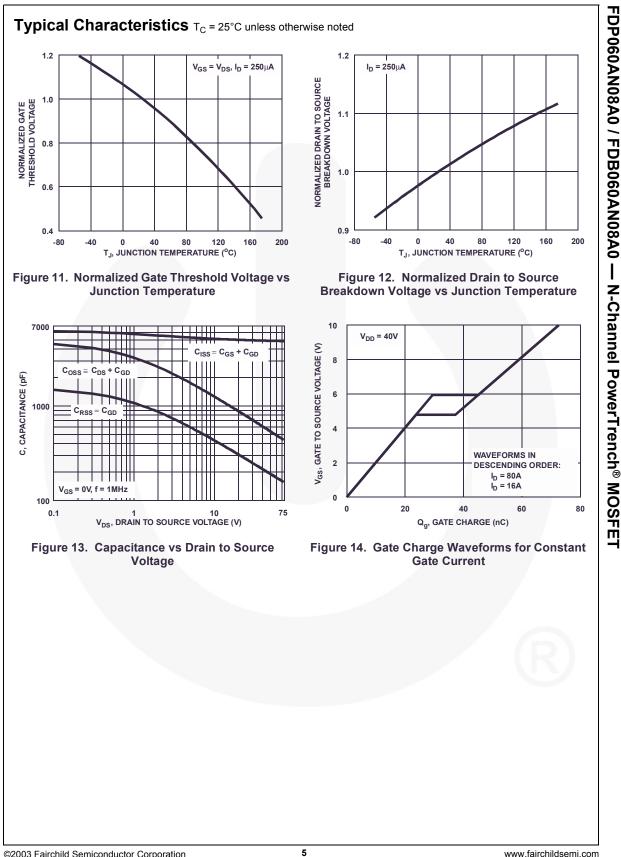


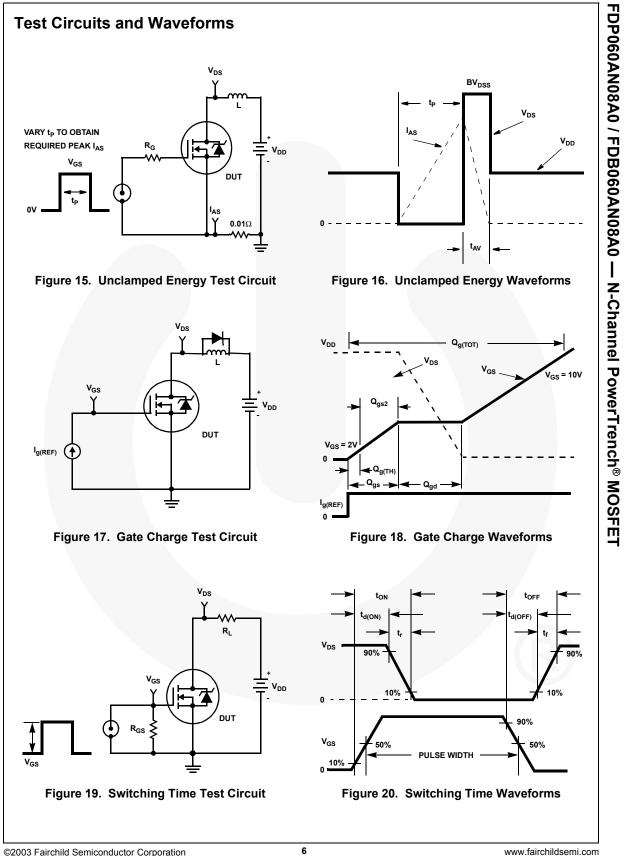
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Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-263 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 10z copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

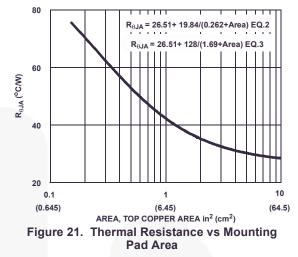
Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

$$R_{\theta JA} = 26.51 + \frac{19.84}{(0.262 + Area)}$$
(EQ. 2)

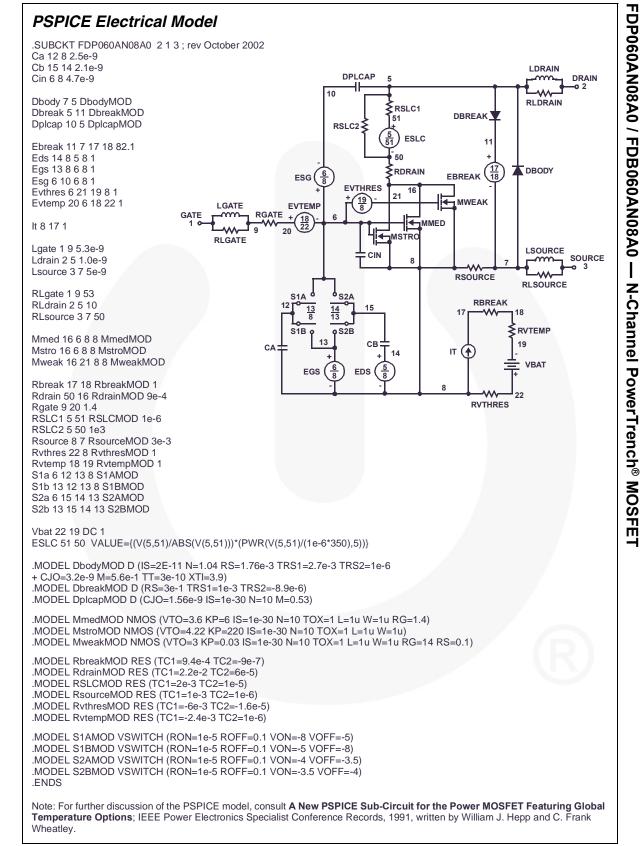
Area in Inches Squared

$$R_{\theta JA} = 26.51 + \frac{128}{(1.69 + Area)}$$
(EQ. 3)
Area in Centimeters Squared

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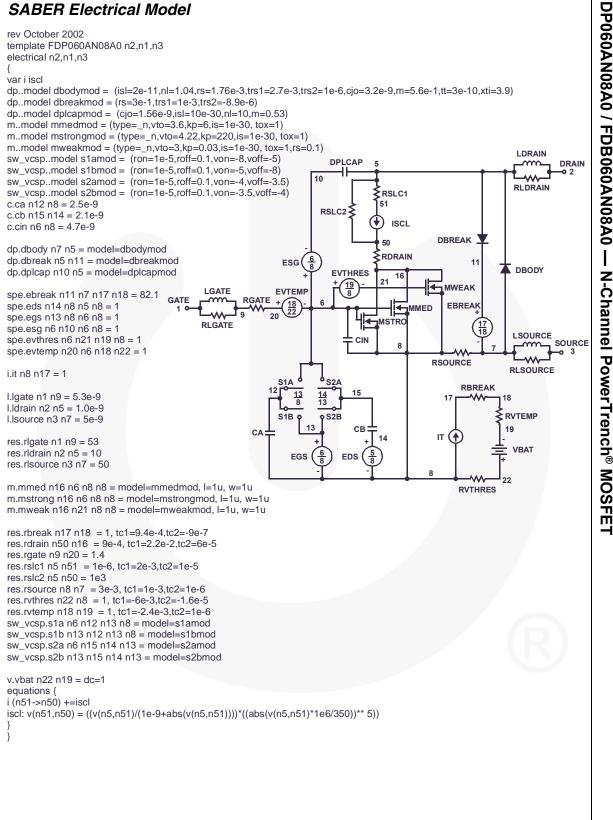


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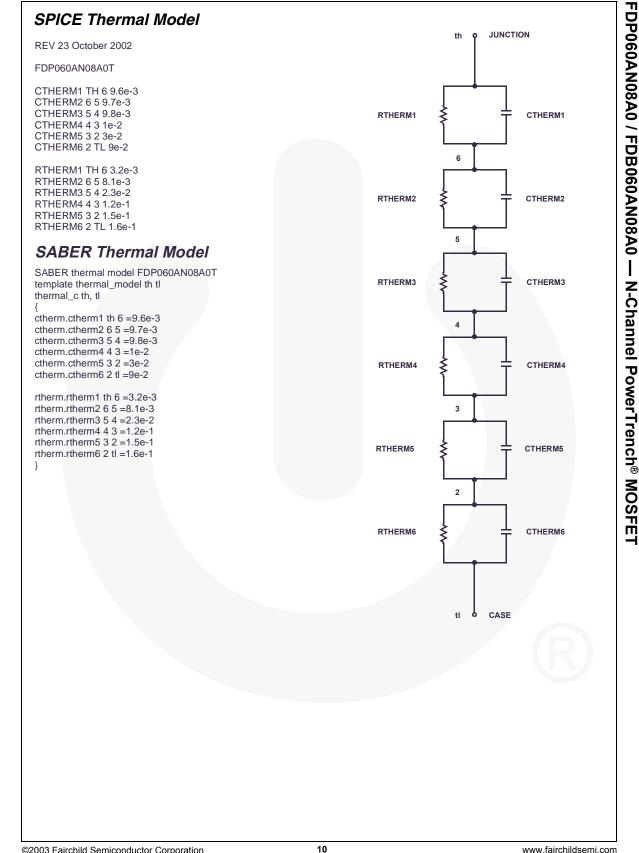


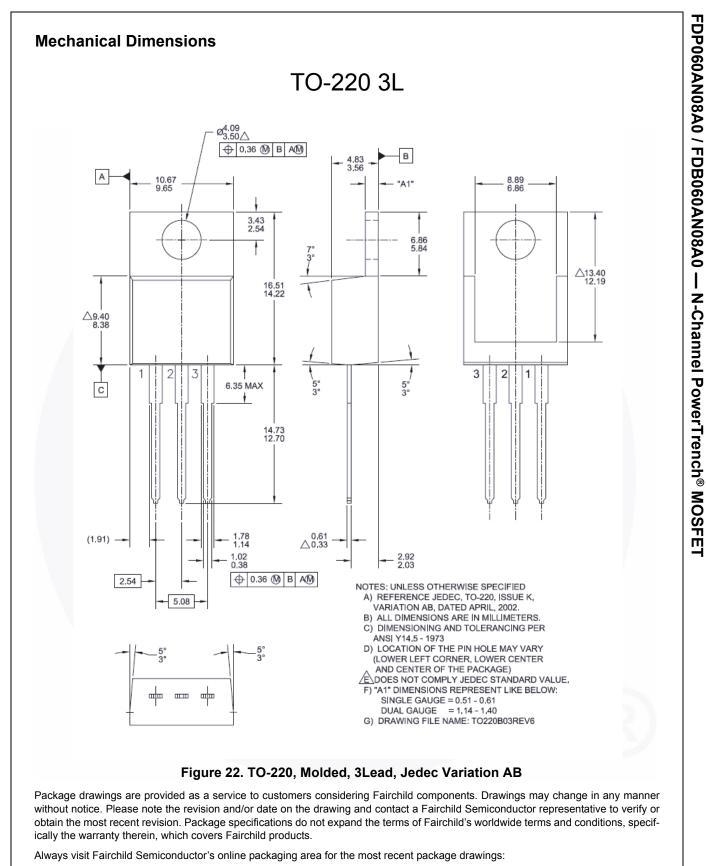
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SABER Electrical Model



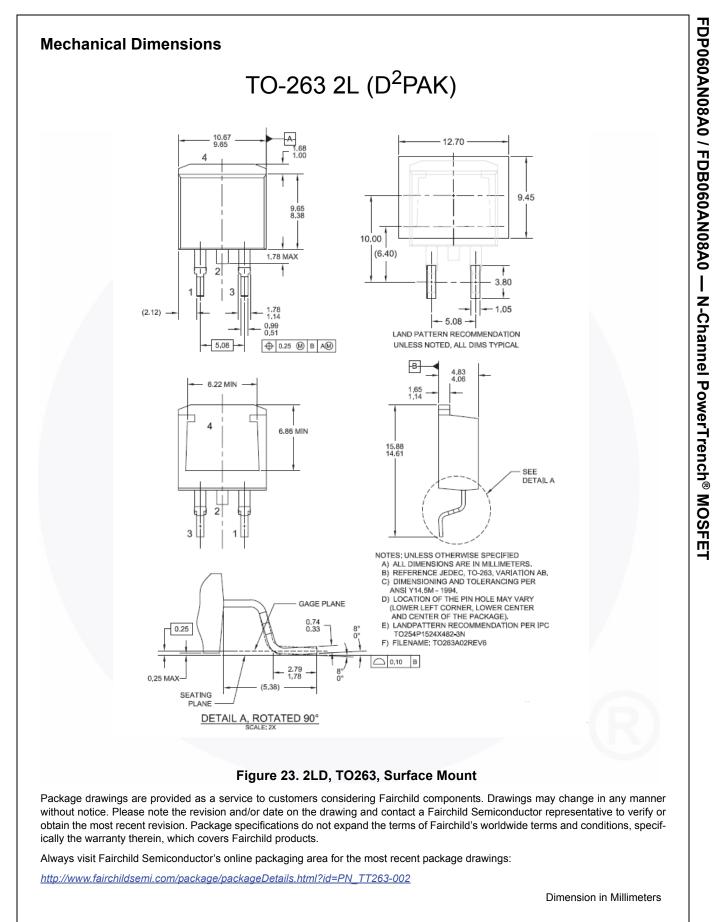
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http://www.fairchildsemi.com/package/packageDetails.html?id=PN_TT220-003

Dimension in Millimeters





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No Identification Needed

Obsolete

Full Production

Not In Production

Datasheet contains specifications on a product that is discontinued by Fairchild

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